

HiPerFRED²

DPF240X400NA

advanced

 $V_{RRM} = 400V$

 $I_{FAV} = 2x 120A$

 $t_{rr} = 45 \, \text{ns}$

High Performance Fast Recovery Diode Low Loss and Soft Recovery Parallel legs

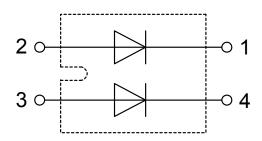
Part number

DPF240X400NA



Backside: isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling





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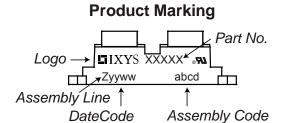
Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			0	V
V _{RRM}	max. repetitive reverse blocking v	roltage	$T_{VJ} = 25^{\circ}C$			400	V
I _R	reverse current, drain current	V _R = 400 V	$T_{VJ} = 25^{\circ}C$			10	μΑ
		$V_R = 400 V$	$T_{VJ} = 150^{\circ}C$			0.5	mΑ
V _F	forward voltage drop	I _F = 120 A	$T_{VJ} = 25^{\circ}C$			1.25	V
		$I_F = 240 \text{ A}$				1.54	V
		I _F = 120 A	T _{VJ} = 150°C			1.06	V
		$I_F = 240 \text{ A}$				1.42	V
I _{FAV}	average forward current	T _C = 80°C	T _{VJ} = 150°C			120	Α
		rectangular d = 0.5					
V _{F0}	threshold voltage		T _{VJ} = 150°C			0.71	V
r _F	slope resistance \(\) for power is	oss calculation only				2.9	mΩ
R _{thJC}	thermal resistance junction to cas	е				0.4	K/W
R _{thCH}	thermal resistance case to heatsing	nk			0.10		K/W
P _{tot}	total power dissipation		$T_C = 25^{\circ}C$			310	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			1.20	kA
CJ	junction capacitance	V _R = 200 V f= 1 MHz	$T_{VJ} = 25^{\circ}C$		187		pF
I _{RM}	max. reverse recovery current	`	$T_{VJ} = 25^{\circ}C$		6		Α
		$I_F = 120 \text{ A}; V_R = 240 \text{ V}$	$T_{VJ} = 125^{\circ}C$		tbd		Α
t _{rr}	reverse recovery time	$-di_F/dt = 200 A/\mu s$	$T_{VJ} = 25^{\circ}C$		45		ns
		J	$T_{VJ} = 125$ °C		tbd		ns





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Package SOT-227B (minibloc)				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					150	Α
T _{VJ}	virtual junction temperatur	е			-40		150	°C
Top	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
$\mathbf{M}_{\mathbf{T}}$	terminal torque				1.1		1.5	Nm
d _{Spp/App}	creenage distance on surf	ace striking distance through air	terminal to terminal	10.5	3.2			mm
d _{Spb/Apb}	creepage distance on sun	ace striking distance through an	terminal to backside	8.6	6.8			mm
V _{ISOL}	isolation voltage	t = 1 second	50/00 II - DMO I		3000			V
	t = 1 minute		50/60 Hz, RMS; I _{ISOL} ≤ 1 mA		2500			V



Part number

D = Diode

P = HiPerFRED

F = ultra fast

240 = Current Rating [A]

X = Parallel legs

400 = Reverse Voltage [V] NA = SOT-227B (minibloc)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPF240X400NA	DPF240X400NA	Tube	10	499554

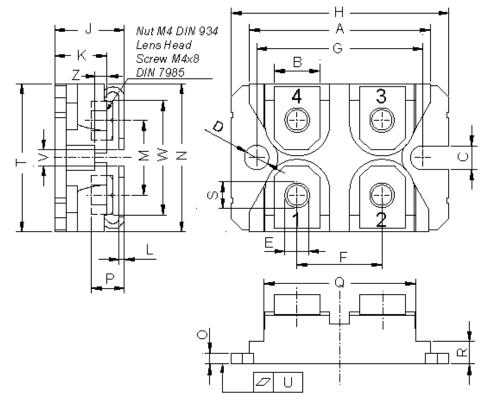
Equivalent Circuits for Simulation			* on die level	T _{VJ} = 150 °C
$I \rightarrow V_0$	R_0	Fast Diode		
V _{0 max}	threshold voltage	0.71		V
R _{0 max}	slope resistance *	1		mΩ



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Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
DIM.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
В	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
Е	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
K	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
M	12.50	13.10	0.492	0.516	
N	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Р	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	

